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November 2013

FQPF10N50CF — N-Channel QFET[®] FRFET[®] MOSFET

FQPF10N50CF

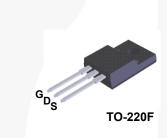
N-Channel QFET[®] FRFET[®] MOSFET 500 V, 10 A, 610 mΩ

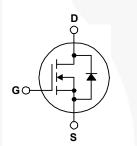
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- 10 A, 500 V, $R_{DS(on)}$ = 610 m Ω (Max.) @ V_{GS} = 10 V, I_D = 5 A
- Low Gate Charge (Typ. 43 nC)
- Low C_{rss} (Typ. 16 pF)
- 100% Avalanche Tested
- Fast Recovery Body Diode





Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

Symbol	Parameter	FQPF10N50CF	Unit
V _{DSS}	Drain-Source Voltage	500	V
ID	Drain Current - Continuous ($T_C = 25^{\circ}C$)	10*	A
	- Continuous (T _C = 100°C)	6.35*	Α
I _{DM}	Drain Current - Pulsed (Note 1)	40*	Α
V _{GSS}	Gate-Source voltage	± 30	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2)	388	mJ
I _{AR}	Avalanche Current (Note 1)	10	Α
E _{AR}	Repetitive Avalanche Energy (Note 1)	14.3	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)	4.5	V/ns
P _D	Power Dissipation $(T_C = 25^{\circ}C)$	48	W
	- Derate above 25°C	0.38	W/°C
T _{J,} T _{STG}	Operating and Storage Temperature Range	-55 to +150	°C
Τ _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds	300	°C

*Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FQPF10N50CF	Unit	
R_{\thetaJC}	Thermal Resistance, Junction to Case, Max.	2.58	00.00	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/W	

Device Marking Device		Package Reel Size		Ta	ape Widt	h Qu	antity		
FQPF10	FQPF10N50CF FQPF10N50CF		TO-220F Tube		N/A		50	50 units	
Electric	al Chai	racteristics T _c = 25°C un	less otherwise noted.						
Symbol		Parameter	Conditio	ons	Min	Тур	Мах	Unit	
Off Charac	teristics								
BV _{DSS}	Drain-Sou	Irce Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA		500			V	
ΔΒV _{DSS} / ΔΤ _J	Breakdown Voltage Temperature Coefficient $I_D = 250 \ \mu$ A, Referenced to 25°C			0.5		V/ºC			
I _{DSS}	Zero Gate Voltage Drain Current		V _{DS} = 500 V, V _{GS} = 0 V				10	μA	
			$V_{DS} = 400 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$				100	μA	
I _{GSSF}	Gate-Bod	y Leakage Current, Forward	$V_{GS} = 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				100	nA	
I _{GSSR}	Gate-Bod	y Leakage Current, Reverse	V_{GS} = -30 V, V_{DS} = 0	0 V			-100	nA	
On Charac	teristics				1				
V _{GS(th)}	Gate Thre	eshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$		2.0		4.0	V	
R _{DS(on)}	Static Drain-Source On-Resistance		V _{GS} = 10 V, I _D = 5 A			0.5	0.61	Ω	
9 _{FS}	Forward Transconductance V_{DS} = 40 V, I _D		V _{DS} = 40 V, I _D = 5 A			15		S	
Dynamic C	haracteris	tics							
C _{iss}	Input Cap	acitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		-	1610	2096	pF	
C _{oss}	Output Ca	apacitance				177	230	pF	
C _{rss}	Reverse 7	Fransfer Capacitance				16	24	pF	
Switching	Characteri	stics							
t _{d(on)}	Turn-On Delay Time		V _{DD} = 250 V, I _D = 10 A			29	67	ns	
t _r	Turn-On F	Rise Time	$R_G = 25 \Omega$			80	170	ns	
t _{d(off)}	Turn-Off [Delay Time				141	290	ns	
t _f	Turn-Off F	all Time		(Note 4)		80	165	ns	
Qg	Total Gate	e Charge	V _{DS} = 400 V, I _D = 10 A V _{GS} = 10 V (Note 4)			43	56	nC	
Q _{gs}	Gate-Sou	rce Charge				7.5		nC	
Q _{gd}	Gate-Drai	n Charge				18.5	1	nC	
Drain-Sou	rce Diode (Characteristics and Maximu	m Ratings						
I _S Maximum Continuous Drain-Source Diode Forward Current					10	Α			
I _{SM}	Maximum Pulsed Drain-Source Diode F		Forward Current				40	Α	
V _{SD}	Drain-Sou	rce Diode Forward Voltage	V _{GS} = 0 V, I _S = 10 A				1.4	V	
t _{rr}	Reverse F	Recovery Time	V _{GS} = 0 V, I _S = 10 A			50		ns	
Q _{rr}	Reverse F	Recovery Charge	dI _F /dt =100 A/μs			0.1		μC	

Notes:

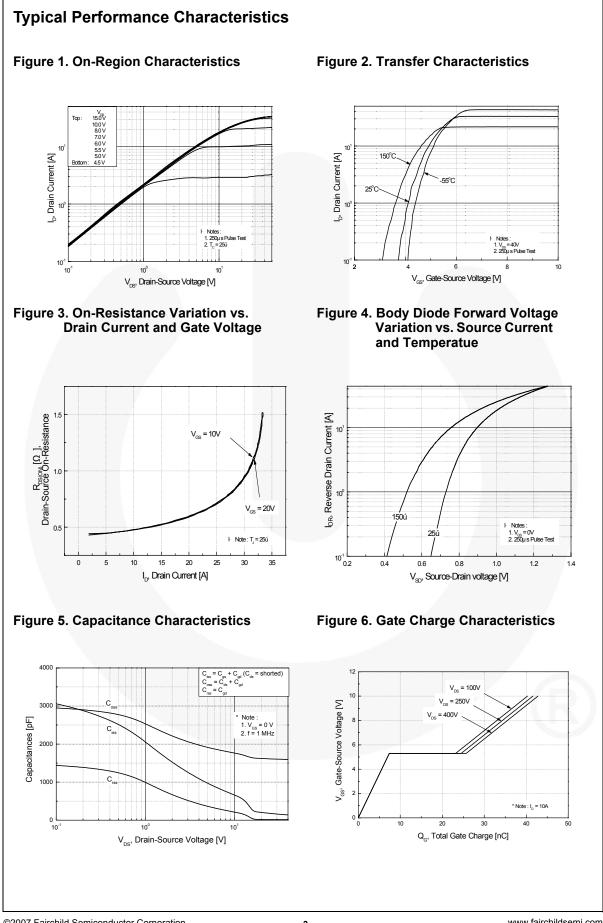
1. Repetitive Rating: Pulse width limited by maximum junction temperature

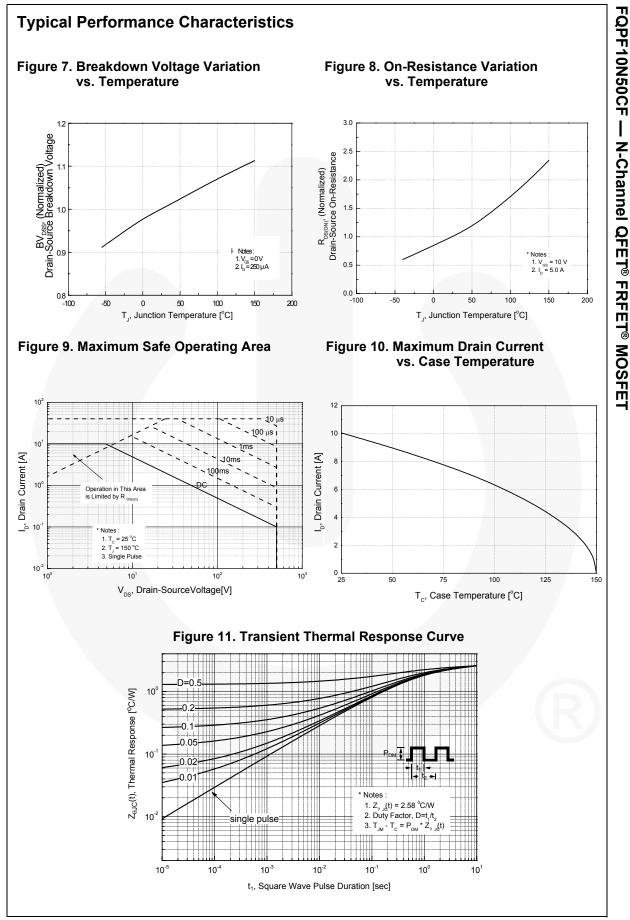
2. L = 7 mH, I_{AS} = 10 A, V_{DD} = 50 V, R_G = 25 $\Omega,$ starting T_J = 25°C

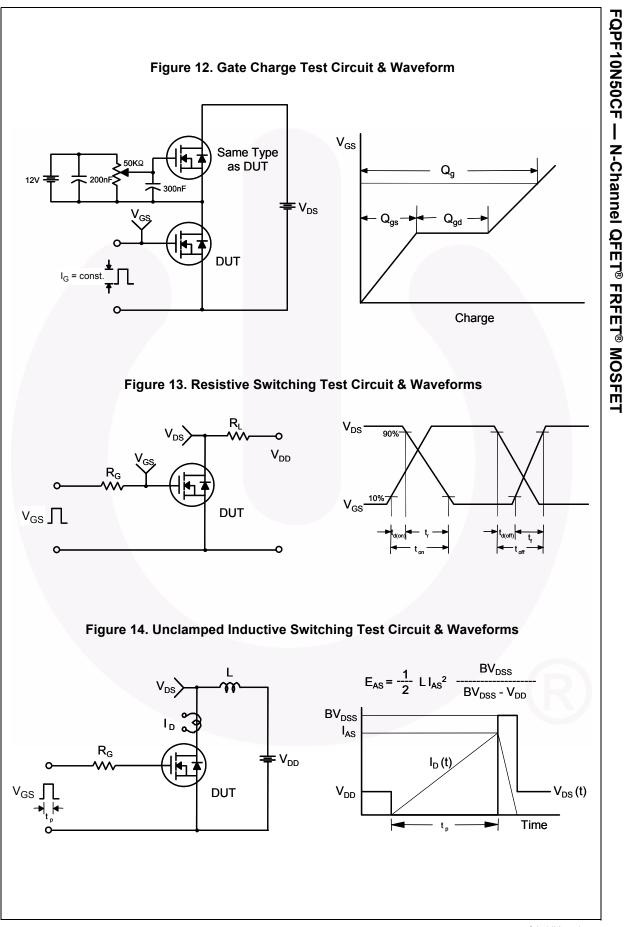
3. I_{SD} \leq 10 A, di/dt \leq 200 A/ $\mu s,~V_{DD} \leq BV_{DSS,}$ starting ~ T_J = 25°C

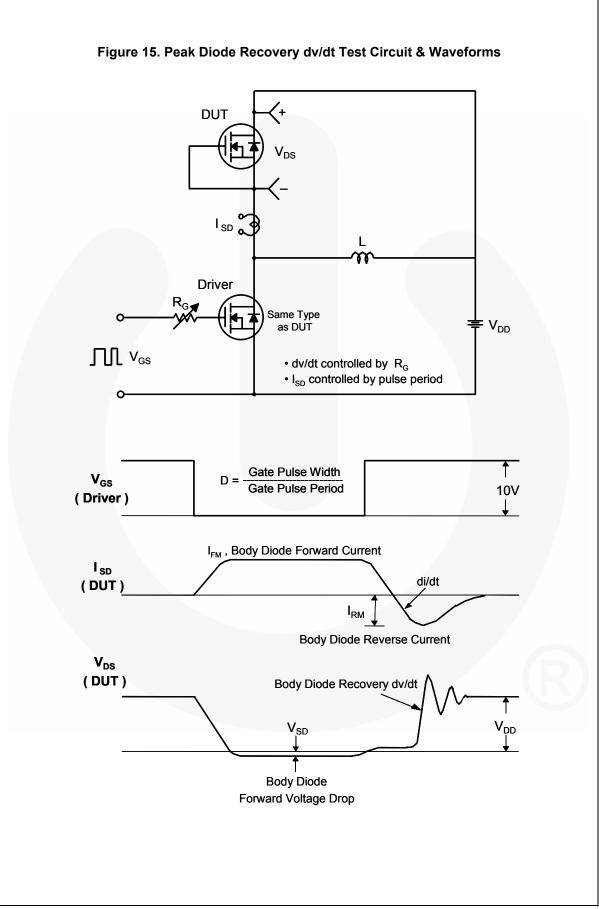
4. Essentially independent of operating temperature.

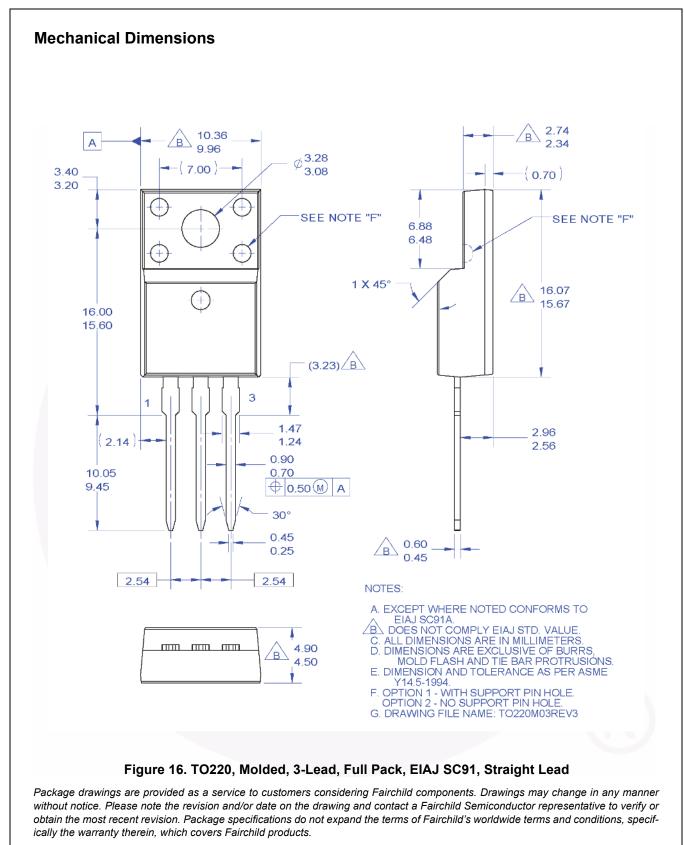
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FQPF10N50CF — N-Channel QFET[®] FRFET[®] MOSFET



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